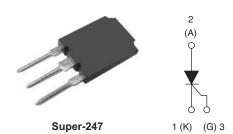


Vishay High Power Products

Phase Control SCR, 70 A



PRODUCT SUMMARY						
V _T at 100 A	< 1.4 V					
I _{TSM}	1400 A					
V_{RRM}	1200/1600 V					

DESCRIPTION/FEATURES



The 70TPS..PbF High Voltage Series of silicon controlled rectifiers are specifically designed for high and medium power switching and phase control applications.

RoHS*

Typical applications are in input rectification (soft start) or AC-switches or high current crow-bar as well as others phase-control circuits. These products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level and lead (Pb)-free ("PbF" suffix).

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
I _{T(AV)}	Sinusoidal waveform	70	۸			
I _{RMS}	Lead current limitation	75	А			
V _{RRM} /V _{DRM}	Range	1200/1600	V			
I _{TSM}		1400	А			
V_{T}	100 A, T _J = 25 °C	1.4	V			
dV/dt		500	V/µs			
dl/dt		150	A/µs			
T _J		- 40 to 125	°C			

VOLTAGE RATINGS				
PART NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA	
70TPS12PbF	1200	1300	15	
70TPS16PbF	1600	1700	15	

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply

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ABSOLUTE MAXIMUM RATIN	GS						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS	
Maximum average on-state current	I _{T(AV)}	T _C = 82 °C, 180° c	onduction half sine w	ave	70		
Maximum continuous RMS on-state current as AC switch	I _{T(RMS)}	Lead current limita	Lead current limitation			Α	
Maximum peak, one-cycle	I	10 ms sine pulse, i	rated V _{RRM} applied		1200		
non-repetitive surge current	I _{TSM}	10 ms sine pulse, r	no voltage reapplied		1400		
Maximum I ² t for fusing	l ² t	10 ms sine pulse, i	rated V _{RRM} applied	Initial T _J = T _J maximum	7200	A ² s	
Maximum i-t for fusing	1-1	10 ms sine pulse, r	no voltage reapplied	maximam	10 200	A-8	
Maximum I $^2\sqrt{t}$ for fusing	I ² √t	t = 0.1 to 10 ms, no	102 000	A²√s			
Low level value of threshold voltage	V _{T(TO)1}				0.916	V	
High level value of threshold voltage	V _{T(TO)2}	T _{.l} = 125 °C			1.21	ľ	
Low level value of on-state slope resistance	r _{t1}	1j = 125 °C			4.138	 0	
High level value of on-state slope resistance	r _{t2}			3.43	mΩ		
Maximum peak on-state voltage	V_{TM}	100 A, T _J = 25 °C		1.4	V		
Maximum rate of rise of turned-on current	dI/dt	T _J = 25 °C		150	A/μs		
Maximum holding current	I _H	T 05 00		200			
Maximum latching current	ΙL	T _J = 25 °C		400			
Maximum reverse and direct lookess surrent	t I _{RRM} /I _{DRM}	T _J = 25 °C			1.0	mA	
Maximum reverse and direct leakage current		T _J = 125 °C	V _R = Rated V _{RRM} /\	15			
Maximum rate of rise of off-state voltage	dV/dt	T _J = 125 °C		500	V/µs		

TRIGGERING							
PARAMETER	SYMBOL		TEST CONDITIONS V				
Maximum peak gate power	P _{GM}	T = 30 µs	T. 00				
Maximum average gate power	P _{G(AV)}	1 = 30 μs		2.5	W		
Maximum peak gate current	I _{GM}			2.5	Α		
Maximum peak negative gate voltage	- V _{GM}			10			
		T _J = - 40 °C		4.0	V		
Maximum required DC gate voltage to trigger	V_{GT}	T _J = 25 °C	Anode supply = 6 V resistive load	1.5			
voluage to aligger		T _J = 125 °C		1.1			
		T _J = - 40 °C		270			
Maximum required DC gate current to trigger	I _{GT}	T _J = 25 °C		100	mA		
		T _J = 125 °C		80			
Maximum DC gate voltage not to trigger	V_{GD}	T _J = 120 °C, V _D	_{RM} = Rated value	0.25	V		
Maximum DC gate current not to trigger	I_{GD}			6	mA		

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THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS	
Maximum junction temperature	range	TJ		- 40 to 125	°C	
Maximum storage temperature r	ange	T _{Stg}		- 40 to 150		
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	0.27		
Maximum thermal resistance, junction to ambient		R _{thJA}		40	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.2		
Approximate weight				6	g	
				0.21	OZ.	
Mounting torque	minimum			6 (5)	kgf · cm	
wounting torque	maximum			12 (10)	(lbf · in)	
Marking device			Coop obula Super 247	70TPS	12	
			Case style Super-247	70TPS	70TPS16	

△R _{thJ-hs} CONDUCTION PER JUNCTION											
DEVICE	s	SINE HALF WAVE CONDUCTION					RECTANGULAR WAVE CONDUCTION				UNITS
DEVICE	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
70TPS	0.078	0.092	0.117	0.172	0.302	0.053	0.092	0.125	0.180	0.306	°C/W

Note

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 $[\]bullet \ \ \, \text{The table above shows the increment of thermal resistance } \, R_{thJ\text{-}hs} \, \text{when devices operate at different conduction angles than DC} \,$

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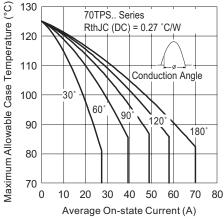


Fig. 1 - Current Rating Characteristics

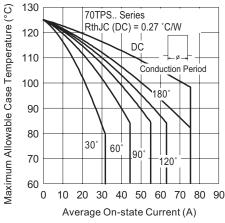


Fig. 2 - Current Rating Characteristics

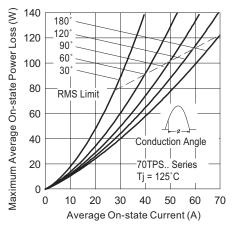


Fig. 3 - On-State Power Loss Characteristics

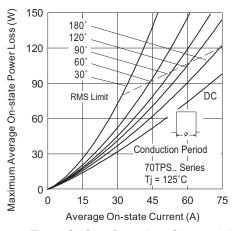


Fig. 4 - On-State Power Loss Characteristics

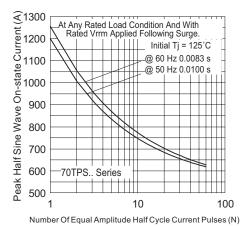


Fig. 5 - Maximum Non-Repetitive Surge Current

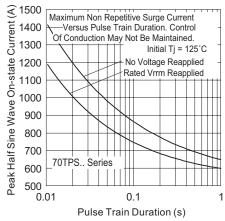


Fig. 6 - Maximum Non-Repetitive Surge Current



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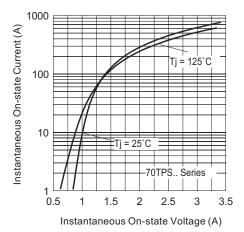


Fig. 7 - On-State Voltage Drop Characteristics

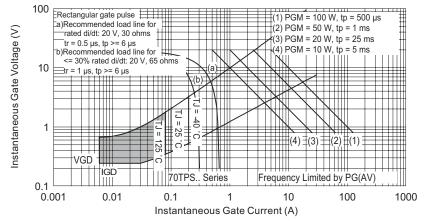


Fig. 8 - Gate Characteristics

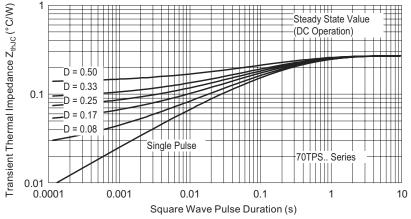


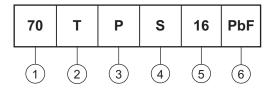
Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

Vishay High Power Products Phase Control SCR, 70 A



ORDERING INFORMATION TABLE

Device code



- 1 Current rating (70 = 70 A)
- 2 Circuit configuration:

T = Thyristor

3 - Package:

P = Super-247

4 - Type of silicon:

S = Standard recovery rectifier

5 - Voltage code x 100 = V_{RRM} - 12 = 1200 V 16 = 1600 V

- 6 • None = Standard production
 - PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS					
Dimensions http://www.vishay.com/doc?95073					
Part marking information	http://www.vishay.com/doc?95070				



Vishay

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